## WIECH

## HTM9G06S075P 75W, 1.8 - 520 MHz LDMOS Amplifier

Preliminary datasheet

#### **Description**

The HTM9G06S075P is an unmatched discrete LDMOS Power Amplifier with 75W saturated output power covering frequency range from 1.8 - 520 MHz, designed for mobile two-way radio applications with high gain, good ruggedness and broadband performance to make it ideal for large-signal, common source amplifier applications in mobile radio equipment.

#### **Features**

• Operating Frequency Range: 1.8 - 520 MHz

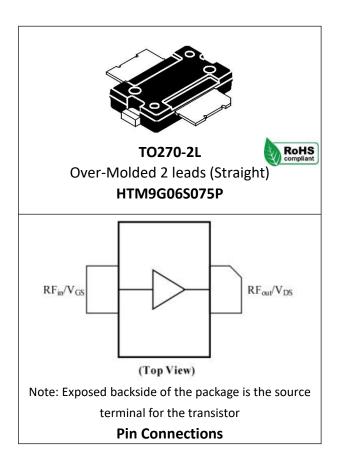
Operating Drain Voltage: 12.5V

Saturation Output Power: 75W

- Excellent thermal stability due to low thermal resistance package
- Enhanced robustness design without device degradation
- Internally integrated enhanced ESD design

#### **Applications**

 Output Stage VHF&UHF Band Mobile Radio



### **Ordering Information**

Part Number	Description
HTM9G06S075P	Reel Package
HTM9G06S075P EVB	450-520MHz EVB

## HTM9G06S075P 75W, 1.8 - 520 MHz LDMOS Amplifier



Preliminary datasheet

#### **RF Characteristics (CW)**

Freq (MHz)	P3dB (dBm)	Eff (%)@P3dB	Gain (dB)	P5dB (dBm)	Eff(%)@P5dB
520	48.40	69.22	21.37	48.79	71.79

Test conditions unless otherwise noted: 25 °C, VDD = +12.5Vdc, IDQ = 400mA CW test on WATECH Application Board

#### RF Characteristics (CW)

Freq (MHz)	P3dB (dBm)	Eff (%)@P3dB	Gain (dB)	P5dB (dBm)	Eff(%)@P5dB
450	49.34	65.31	17.55	49.76	68.02
485	48.62	67.58	18.66	49.00	69.93
520	48.49	65.48	18.15	48.89	67.77

Test conditions unless otherwise noted: 25 °C, VDD = +12.5dc, IDQ= 400mA CW test on WATECH Application Board

#### **Absolute Maximum Ratings**

Parameter	Range/Value	Unit
Drain voltage (VDSS)	-0.5 to +65	V
Gate voltage (V <sub>GS</sub> )	-6 to +10	V
Storage Temperature (Tstg)	-55 to +150	°C
Junction Temperature (T <sub>J</sub> )	+225	°C

#### **Electrical Specification**

#### **DC Characteristics**

Parameter	Conditions	Min	Тур	Max	Unit
Breakdown Voltage V(BR)DSS	Vgs=0V, Ids=203uA	60	63	-	V
Gate-Source Threshold Voltage Vgs(th)	Vgs=Vds, Ids=203uA	0.9	1.2	1.9	V
Drain Leakage Current loss	Vgs=0V, Vds=50V	-	0.5	-	uA
Gate Leakage Current Igss	Vgs=5V, Vds=0V	-	0.05	-	uA

#### **Load Mismatch Test**

Condition	Test Result
VSWR=65:1, at all Phase Angles, $V_{DD}$ = +17Vdc, $I_{DQ}$ = 400mA,	No Device
CW PAVG = 75W, Frequency 520MHz test on WATECH Application Board	Degradation

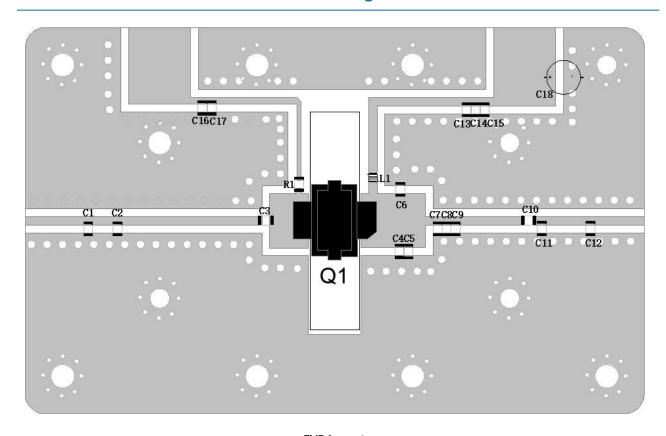
#### **Thermal Information**

Parameter	Condition	Value (Typ)	Unit
Thermal Resistance	Tcase= 25°C, V <sub>DD</sub> = +12.5Vdc, I <sub>DQ</sub> = 400mA,	1 17	°C /W
Junction to Case (Rтн)	PAVG = 48.88 dBm (75W), CW signal	1.17	C / VV



Preliminary datasheet

## HTM9G06S075P 450-520MHz Reference Design



**EVB Layout** 

## Bill of Materials (BoM) - HTM9G06S075P 450-520 MHz Reference Design

Reference	Value	Description	Manufacturer	P/N
Q1	-	75W, 450 - 520 MHz	Watech	HTM9G06S075P
		LDMOS PA		
C1,C2	10pF	MLCC	Murata	GRM21A5C2E100FW01
С3	100pF	MLCC	Murata	GRM21A5C2E101FW01
C4	43pF	MLCC	Murata	GRM21A5C2E430FW01
C5	33pF	MLCC	Murata	GRM21A5C2E330FW01
C6	47pF	MLCC	Murata	GRM21A5C2E470FW01
C7	15pF	MLCC	Murata	GRM21A5C2E150FW01
C8	13pF	MLCC	Murata	GRM21A5C2E130FW01
C9	9.1pF	MLCC	Murata	GRM21A5C2E9R1FW01

## HTM9G06S075P

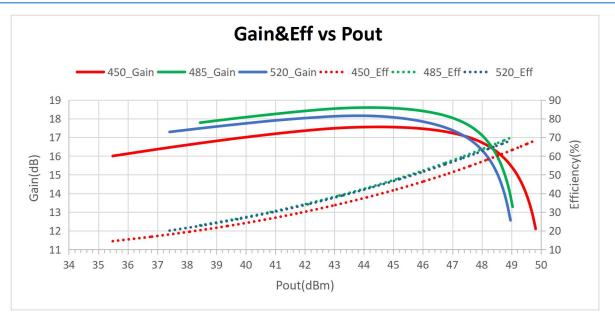
Preliminary datasheet



### 75W, 1.8 - 520 MHz LDMOS Amplifier

				·	
C10	820pF	MLCC	Dalicap	DLC70B821JW501XT	
C11	5PF	MLCC	Murata	GRM21A5C2E5R0FW01	
C12	13PF	MLCC	Murata	GRM21A5C2E130FW01	
C13	30pF	MLCC	Dalicap	DLC70B300JW501XT	
C14,C17	1nF	MLCC	Dalicap	DLC70B102JW501XT	
C15,C16	4.7uF	MLCC	YAGEO	CC1210KKX5R9BB475	
R1	27 Ω	Chip Resistor	КОА	SMD 0805	
L1	3 turns d=6mm	Air Inductor	1mm copper wire		
C18	1000uF	AEC	Chongx VEHT	100V 18*35mm	
РСВ	Rogers 4350B (er = 3.5), thickness = 20 mil (0.508 mm); thickness copper plating = 35 μm , gold plated。				

#### **Performance Plots**

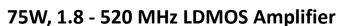


CW, Gain and Efficiency vs Pout

Test conditions unless otherwise noted: 25 °C, VDD = +12.5Vdc, IDQ= 400mA CW test on WATECH Application Board

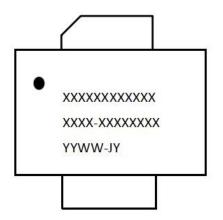
## HTM9G06S075P

Preliminary datasheet



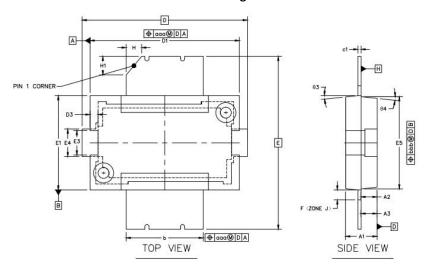


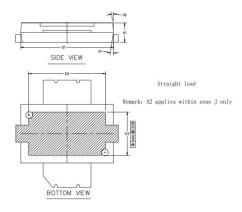
#### **Package Marking and Dimensions**



- Line1 (fixed): Device name in work order
- Line2 (unfixed): Mark Lot Number in work order (Sample: E596-20140001)
- Line3 (unfixed): Date Code + JY(Fixed)
  This Marking SPEC only stipulates the
  content of Marking. For marking
  requirements such as font and size, please
  refer to the latest version of "Watech
  Product Printing Specification"

#### Marking









## 75W, 1.8 - 520 MHz LDMOS Amplifier

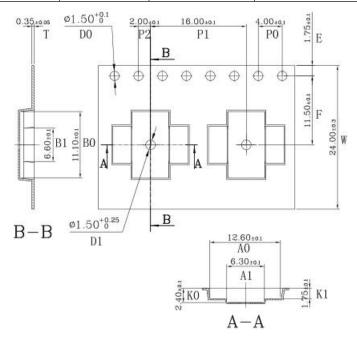
Preliminary datasheet

		SYMBOL	MIN	NOM	MAX
TOTAL THICKNESS		A1	1.98	2.03	2.08
		A2	1.02	1.045	1.07
MOLD THICKNESS		A3	0.99	1.04	1.09
L/F THICKNESS	00	C1		0.203 REF	
BODY SIZE	X	D	10.57	10.67	10.77
BODT SIZE	Y	E	11.08	11.18	11.28
CION SIZE	×	D2		7.37 MIN	
CION SIZE	Y	E2		3.81 MIN	
MOLD LENGTH		D1	9.6	9.65	9.7
LENGTH		D3	0.41	0.51	0.61
MOLD WIDTH		E1	6.05	6.1	6.15
		E3	1.48	1.58	1.68
WIDTH		E4	1.68	1.78	1.88
		E5	5.91	5.96	6.01
ZONE WIDTH		F	0.64 BSC		
LEAD WIDTH		ь	4.9	4.98	5.06
PACKAGE EDGE TOLER	ANCE	aaa	0.1		
LEAD OFFSET		bbb	0.2		
		01	7.	9.	111
TAPER ANGLE		92	4*	6°	8*
INI LIS AITOLL		93	4'	6*	8.
		94	4.	6°	8.
PIN1 SIZE		Н		1 REF	
		H1	1.2 REF		

#### **Package Dimensions**

### **Tape and Reel Information**

Package Type	Reel Size(inch)	Qty/Reel(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)
TO270 (Straight)	13inch	1500	1500	7500



**Tape & Reel Packaging Descriptions** 

# WATECH

## HTM9G06S075P 75W, 1.8 - 520 MHz LDMOS Amplifier

Preliminary datasheet

#### **Handling Precautions**

Parameter	Grade
Moisture Sensitivity Level MSL	3

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114
ESD – Me Model (MM)	Class A	EIA/JESD22-A115
ESD – Charged Device Model (CDM)	Class III	JESD22-C101



#### **RoHS Compliance**

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

#### **Datasheet Status**

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification

#### **Abbreviations**

Acronym	Definition
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor
CW	Continuous Waveform

#### **Revision history**

Document ID	Datasheet Status	Release Date	Revision Version
Rev 1.0	Preliminary	March 2024	Preliminary
Rev 1.1	Preliminary	April 2024	Update Rтн test result

## HTM9G06S075P 75W, 1.8 - 520 MHz LDMOS Amplifier



Preliminary datasheet

For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

• Web: <u>www.watechelectronics.com</u>

Email: MKT@huatai-elec.com

For technical questions and application information:

Email: MKT@huatai-elec.com

#### **Important Notice**

Information in this document is believed to be accurate and reliable. However, WATECH does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

"Typical" parameters are the average values expected by WATECH in large quantities and are provided for information purposes only. All information and specifications contained herein are subject to change without notice and customers should obtain and verify the latest relevant information before placing orders for WATECH products.

The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information.

Applications that are described herein for any of these products are for illustrative purposes only. WATECH makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using WATECH products, and WATECH accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the WATECH product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third-party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

WATECH products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety- critical systems or equipment, nor in applications where failure or malfunction of a WATECH product can reasonably be expected to result in personal injury, death or severe property or environmental damage. This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.